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Design of the ASIC readout scheme for the JUNO-TAO



experiment

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Introduction to JUNO-TAO (Taishan Antineutrino Observatory)



TAO is a satellite experiment of the Jiangmen **Underground Neutrino Observatory (JUNO)**

precisely measure the reactor antineutrino spectrum with

	KLauS6
Target	SiPM calorimetry
Designer	Heidelberg
Input channels	36
Dynamic range	4.5 fC ~ 450 pC 0.03 p.e.~ 2800 p.e.
ADC	40MHz 10/12 bit SAR ADC
Dead time	0.6 us
Time resolution	200 ps
Power consumption per channel	26.6 uW(Power Pulsing) 3.6 mW(full operation)

Introduction to Klaus6

- Input stage → Buffer & distribute signal current, SiPM bias voltage tuning
- **2** integration branches \rightarrow Different charge range
- 2 comparators → Timestamp & ADC start, self-selected gain
 - Leading edge current discrimination
- Developed by University Heidelberg

- a record energy resolution of < 2% at 1 MeV.
- **TAO will be operated at -50°C to reduce the influences** on the energy resolution from the SiPM dark noise.
- Approximately 10 m² SiPMs will be installed on the inner surface of a copper shell
 - The SiPMs are packaged in 4024 SiPM tiles
 - The coverage of the SiPM tiles is approximately 95%
 - The photon detection efficiency of the SiPMs must reach
 - 50%, which yields a photon detection of \sim 4500 photoelectron (p.e.) per MeV.
 - Each tile with dimensions of about 50 mm × 50 mm consists of 8 × 8 SiPMs (6 × 6 mm^2 for each SiPM).
- The backup readout scheme for JUNO-TAO

Tab. Key Parameters of Klaus6

36-channel SiPM readout

- UMC 180nm CMOS technology
- Application
 - **Calorimetry for future linear collider experiments**



Fig. Structure Diagram



Performance Measurement With Charge injection



Performance Measurement With SiPMs

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- **8 x 8 SiPM elements, 6 mm x 6 mm for each**
- **2** SiPMs are connected in parallel in one readout channel
- Illuminated with a pulsed LED light source on top of the tile
- The same bias voltage is used for all channels
- Charge spectra were measured (HG) both at -50 °C and -60°C
- Only results at -50 °C are shown, since the differences between -50°C and -60 °C are not significant.
- Clear SPE signals can be observed for all three tested SiPMs from different vendors.



Over voltage = 5 V

Channel ID

- Gains in 3 branches (HG 1:1, MHG 1:7 and LG 1:40) have been characterized for 4 chips at low temperatures, which shows good linearity.
- The input capacitance variations (5%) contribute to the non-uniformity between channels.



Fig. Deadtime Measurement with Charge injection

Fig. ENC Measurement with 4 ASICs

- The dead time of the KLauS chip is less than 600 ns, which meets the requirement of 1 μs for IBD detection.
- Small Equivalent Noise Charge ENC = 4.5fC, which Meets the requirement that ENC must be less than 0.1 p.e.



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Fig. HG charge spectra at -50 °C, OV ~2.5V, HG (1:1), Channel 0 - 31

Fig. HG charge spectra at -50°C with Hamamatsu, SensL and FBK



Fig. Power Dissipation

- The testing results of the ASIC readout prototype look quite promising at low temperatures.
- It has been proved that the design of the ASIC readout scheme is solid and robust.
- The performance of the KLauS6 chip can meet TAO's requirements.
- The power dissipation is increased at low temperatures, which induced a potential risk on long term reliability. But it has no effect on the performance of Klaus6.